



DS - 1KL3B

The DS - 1KL3B, a silicon photodiode mounted in durable, hermetically sealed TO - 18metal can package, provides years of reliable performance even under demanding conditions such as use outdoors.

FEATURES

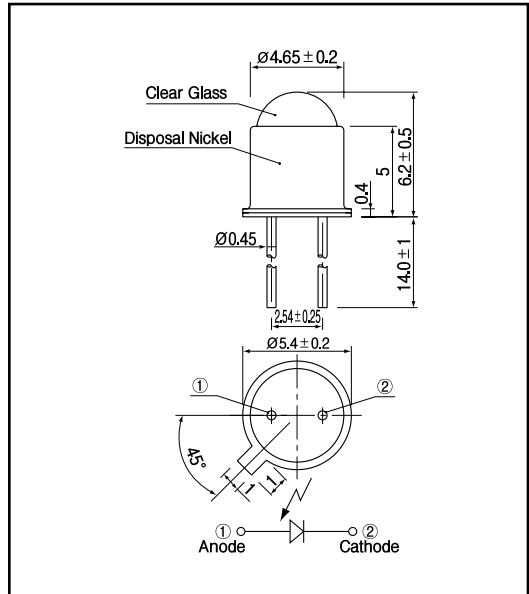
- Narrow angular response
- Durable
- High reliability in demanding environments

APPLICATIONS

- Optical counters
- Optical switches
- Infrared sensors
- Encoders
- Smoke detectors
- Car electronics

DIMENSIONS

(Unit : mm)



MAXIMUM RATINGS

($T_a=25$)

Item	Symbol	Rating	Unit
Reverse voltage	V_R	20	V
Operating temp.	$T_{opr.}$	- 25 ~ + 120	
Storage temp.	$T_{stg.}$	- 30 ~ + 150	
Soldering temp. ^{*1}	$T_{sol.}$	260	

*1. For MAX.5 seconds at the position of 2 mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

($T_a=25$)

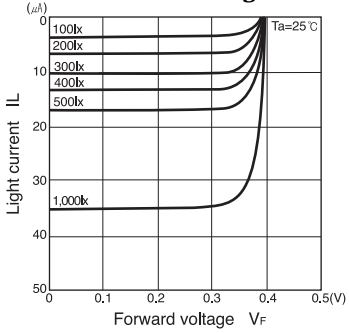
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Open circuit voltage	V_{oc}	$E_v = 1,000lx^{-2}$	18	0.4		V
Short circuit current	I_{sc}			35		μA
Dark current	I_d	$V_R = 5V$			0.1	μA
Curve factor	C.F.		0.55			-
Capacitance	C_t	$V = 0V, f = 1MHz$		50		pF
Temperature coefficient of V_{oc}	t			- 2.2		mV/
Temperature coefficient of I_{sc}	t			0.18		%/
Spectral sensitivity				450 ~ 1,050		nm
Peak wavelength	ρ			900		nm
Half angle				± 15		deg.

*2. Color temp. = 2856K standard Tungsten lamp

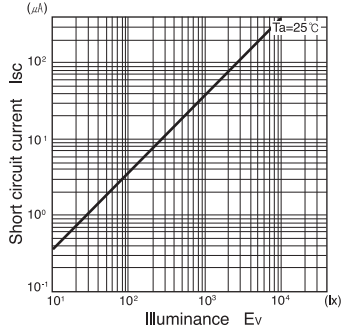


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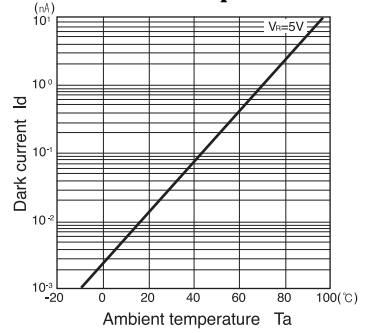
Light current Vs. Forward voltage



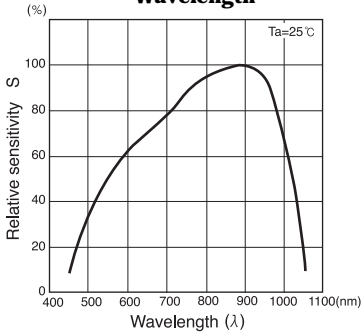
Short circuit current Vs. Illuminance



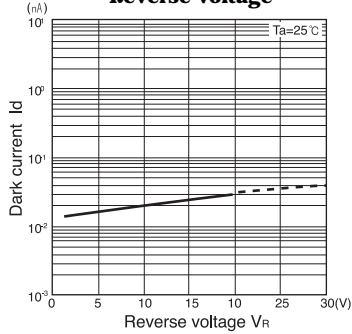
Dark current Vs. Ambient temperature



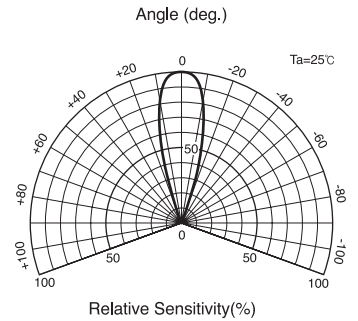
Relative sensitivity Vs. Wavelength



Dark current Vs. Reverse voltage



Radiant Pattern



Capacitance between terminals Vs. Reverse voltage

